NSN 5961-00-892-1007

Diode Semiconductor Device - Page 1 of 1



view Online at https://aerobasegroup.com/hsn/5961-00-892-1007
Inclosure Material:
Glass
Overall Length:
0.210 inches
Terminal Length:
1.125 inches
Overall Diameter:
0.281 inches
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
18.0 regulator voltage
Current Rating Per Characteristic:
25.00 milliamperes repetitive peak forward current
Power Rating Per Characteristic:
1.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius case
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
80131-release2505 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0